

Surface Mount Schottky Barrier Rectifier
Reverse Voltage - 20 to 200 V
Forward Current - 3 A

FEATURES

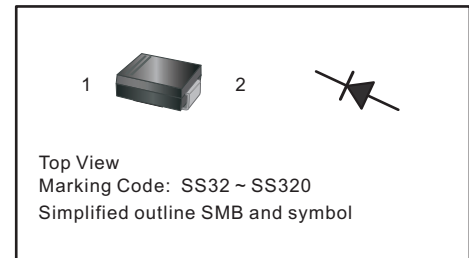
- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: SMB
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 95mg (0.0034oz)

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | Cathode |
| 2 | Anode |



Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

| Parameter | Symbols | SS32B | SS34B | SS36B | SS38B | SS310B | SS312B | SS315B | SS320B | Units |
|---|-----------------|------------|-------|-------|----------|--------|--------|--------|--------|-------|
| Maximum Repetitive Peak Reverse Voltage | V_{RRM} | 20 | 40 | 60 | 80 | 100 | 120 | 150 | 200 | V |
| Maximum RMS voltage | V_{RMS} | 14 | 28 | 42 | 56 | 70 | 84 | 105 | 140 | V |
| Maximum DC Blocking Voltage | V_{DC} | 20 | 40 | 60 | 80 | 100 | 120 | 150 | 200 | V |
| Maximum Average Forward Rectified Current | $I_{F(AV)}$ | 3.0 | | | | | | | | A |
| Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method) | I_{FSM} | 80 | | | | | | | | A |
| Max Instantaneous Forward Voltage at 3 A | V_F | 0.55 | 0.70 | | 0.85 | | 0.95 | | V | |
| Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Reverse Voltage $T_a = 100^\circ\text{C}$ | I_R | 0.5 5 | | | 0.3 3 | | | | mA | |
| Typical Junction Capacitance ⁽¹⁾ | C_j | 450 | | | 400 | | | | pF | |
| Typical Thermal Resistance ⁽²⁾ | $R_{\theta JA}$ | 60 | | | | | | | | °C/W |
| Operating Junction Temperature Range | T_j | -55 ~ +150 | | | | | | | | °C |
| Storage Temperature Range | T_{stg} | -55 ~ +150 | | | | | | | | °C |

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.



Fig.1 Forward Current Derating Curve

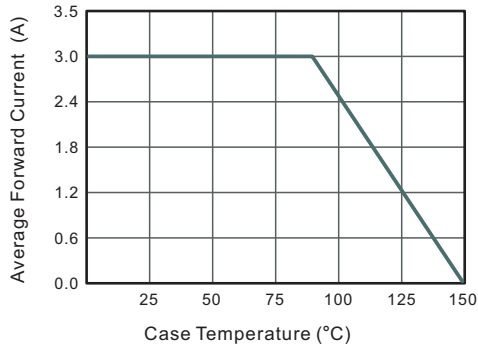


Fig.2 Typical Reverse Characteristics

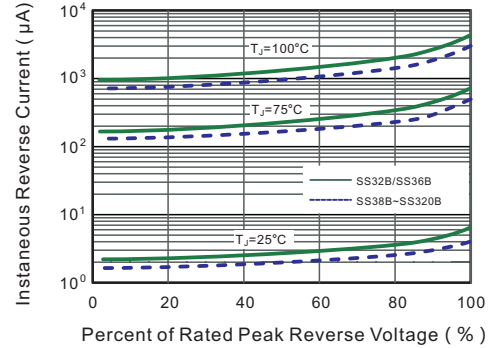


Fig.3 Typical Forward Characteristic

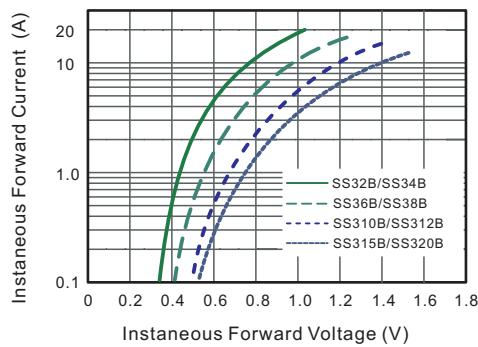


Fig.4 Typical Junction Capacitance

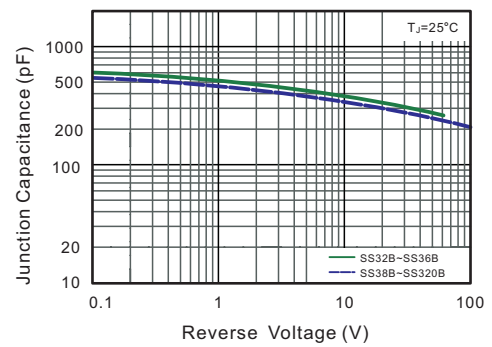


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

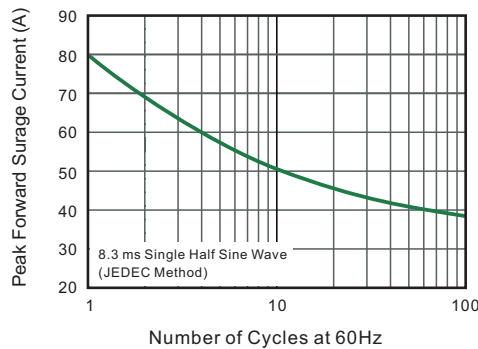
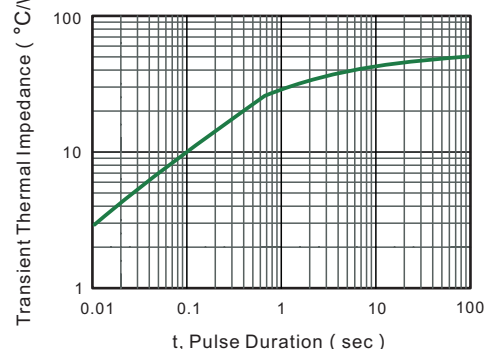


Fig.6- Typical Transient Thermal Impedance

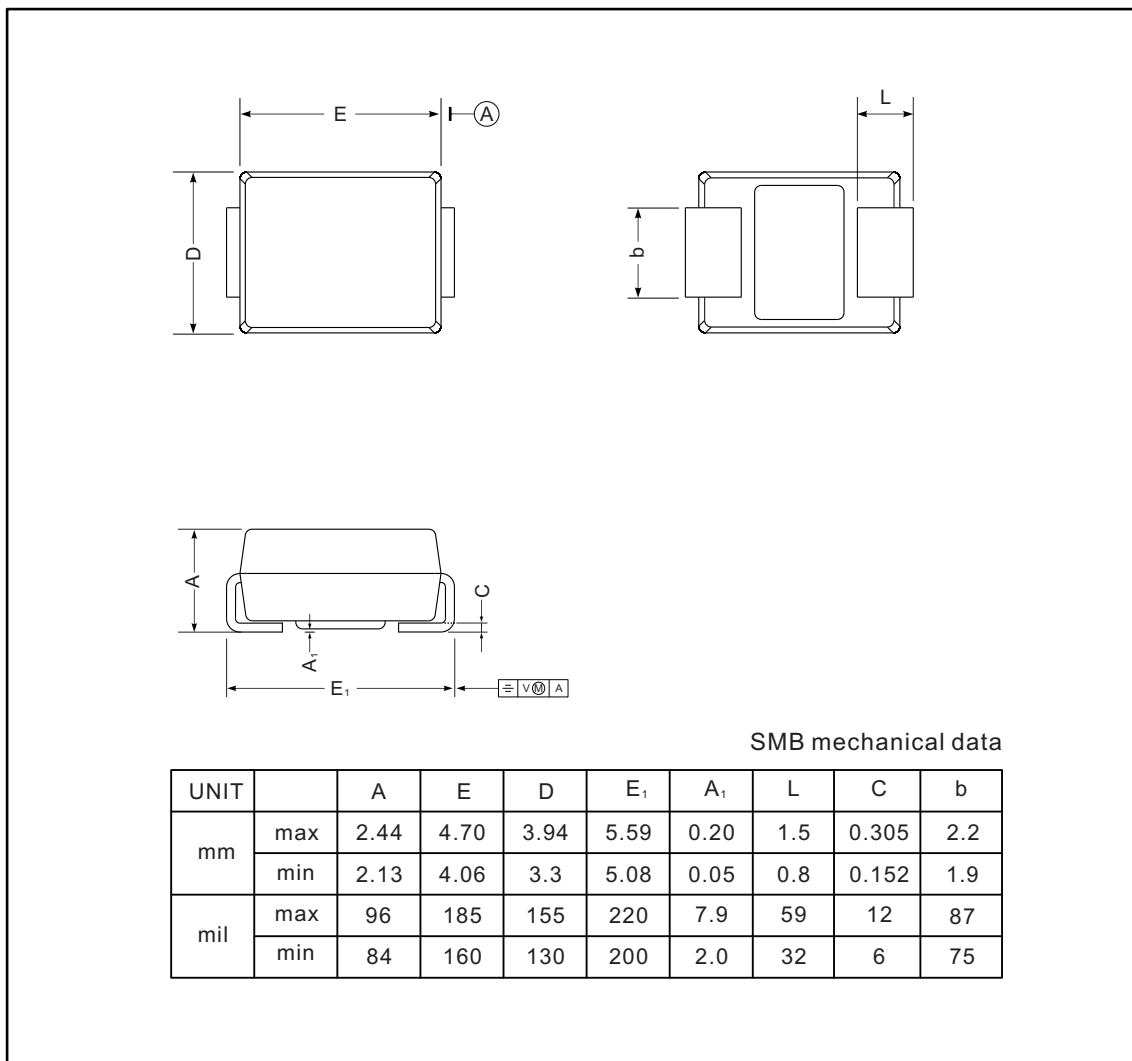




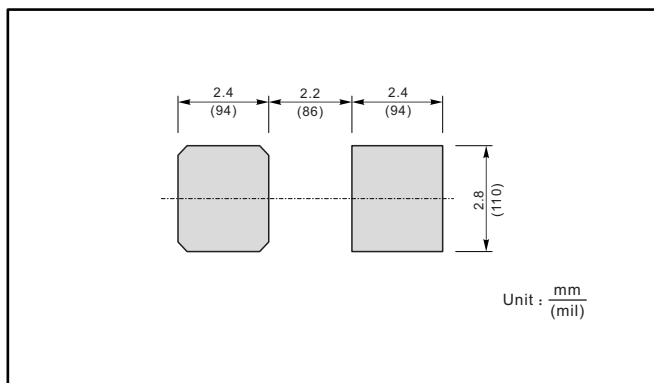
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SMB



The recommended mounting pad size



Marking

| Type number | Marking code |
|-------------|--------------|
| SS32B | SS32 |
| SS34B | SS34 |
| SS36B | SS36 |
| SS38B | SS38 |
| SS310B | SS310 |
| SS312B | SS312 |
| SS315B | SS315 |
| SS320B | SS320 |

单击下面可查看定价，库存，交付和生命周期等信息

[>>JINGDAO\(晶导微\)](#)